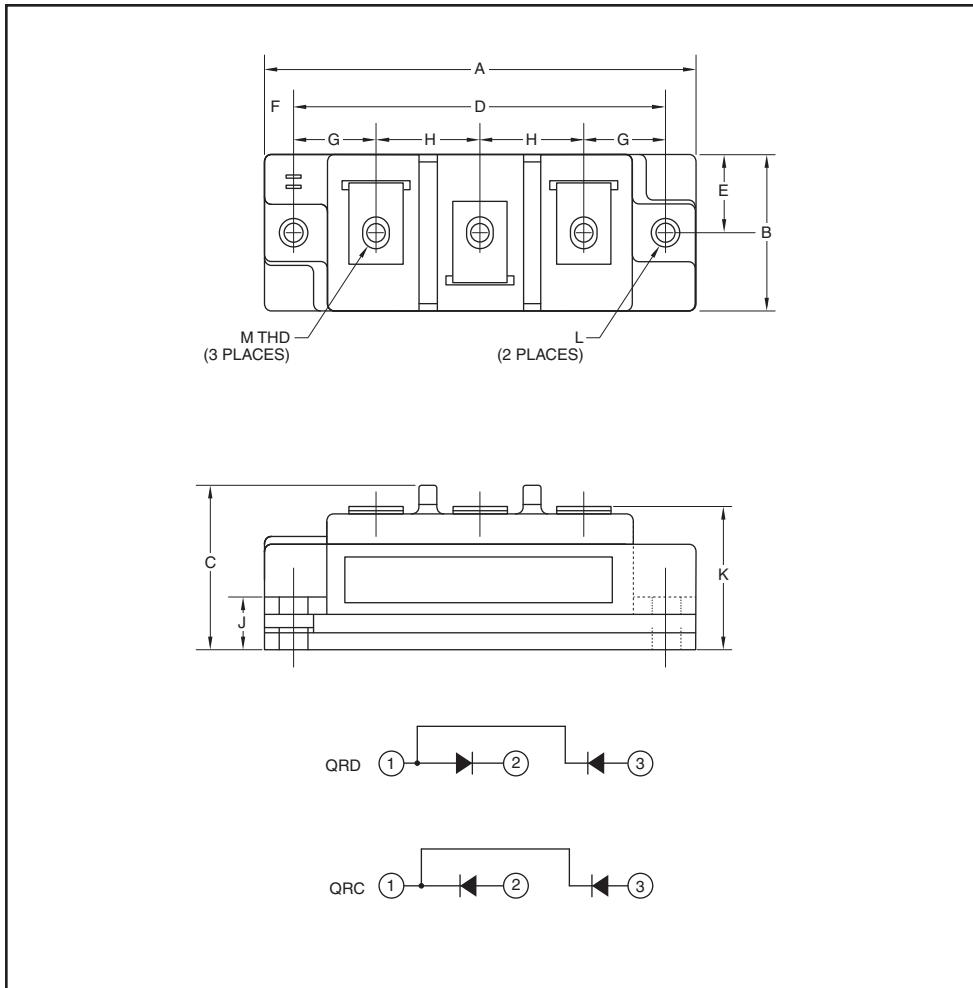


**Fast Recovery  
Diode Module  
100 Amperes/3300 Volts**



**Outline Drawing and Circuit Diagram**

Dimensions	Inches	Millimeters
A	3.70	94.0
B	1.34	34.0
C	1.40	35.6
D	3.15	80.0
E	0.67	17.0
F	0.28	6.99

Dimensions	Inches	Millimeters
G	0.67	17.1
H	0.91	23.0
J	0.36	9.0
K	1.18	30.0
L	0.216 Dia.	5.5 Dia.
M	#10-32	#10-32



**Description:**

High voltage diodes feature highly insulating housings that offer enhanced protection by means of greater creepage and strike clearance distance for many demanding applications like medium voltage drives and auxiliary traction applications.

**Features:**

- Alumina Ceramic Substrate for Low Thermal Impedance
- Copper Baseplate
- Fast Recovery Time (1.2  $\mu$ s max.)
- Industry Standard Packages Allow Common Bus Work to Complementary High Isolation Diodes
- No Additional Insulation Components Required

**Applications:**

- High Voltage Power Supplies
- Medium Voltage Drives
- Motor Drives
- Traction

QR\_3310002

 Fast Recovery Diode Module  
 100 Amperes/3300 Volts

**Absolute Maximum Ratings,  $T_j = 25^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	QRD3310002	QRC3310002	Units
Repetitive Peak Reverse Blocking Voltage	RRM	3300	Volts	
Non-Repetitive Peak Reverse Blocking Voltage	$V_{RSM}$	$V_{RRM} + 100$	Volts	
Average Forward Current	$T_C = 80^\circ\text{C}$	$I_F(\text{avg})$	60	Amperes
	$T_C = 25^\circ\text{C}$	$I_F(\text{avg})$	90	Amperes
Forward Current (Pulse)	IFM	200	Amperes	
Operating Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$	
Storage Temperature	T <sub>stg</sub>	-40 to 150	$^\circ\text{C}$	
Maximum Mounting Torque, #10-32 Mounting Screw	—	26	in-lb	
Maximum Terminal Torque, #10-32 Terminal Screw	—	26	in-lb	
Module Weight (Typical)	—	250	Grams	
V Isolation (60 Hz, Circuit to Base, All Terminals Shorted, t = 1 sec.)	$V_{RMS}$	6000	Volts	

**IGBT Electrical Characteristics,  $T_j = 25^\circ\text{C}$  unless otherwise specified**

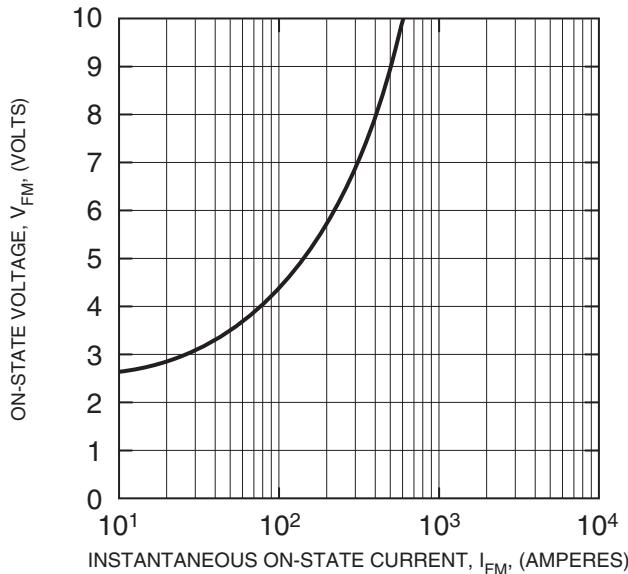
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Peak Reverse Leakage Current	$I_{RRM}$	Rated $V_{RRM}$	—	—	5	mA
Peak On-State Voltage	$V_{FM}$	$I_F = 100\text{A}$	—	3.3	4.3	Volts
Reverse Recovery Time	$t_{rr}$	$I_F = 100\text{A}$ , $\text{di}/\text{dt} = -200\text{A}/\mu\text{s}$	—	—	1.2	$\mu\text{s}$
Reverse Recovery Charge	$Q_{rr}$	$I_F = 100\text{A}$ , $\text{di}/\text{dt} = -200\text{A}/\mu\text{s}$	—	25	—	$\mu\text{C}$

**Thermal and Mechanical Characteristics,  $T_j = 25^\circ\text{C}$  unless otherwise specified**

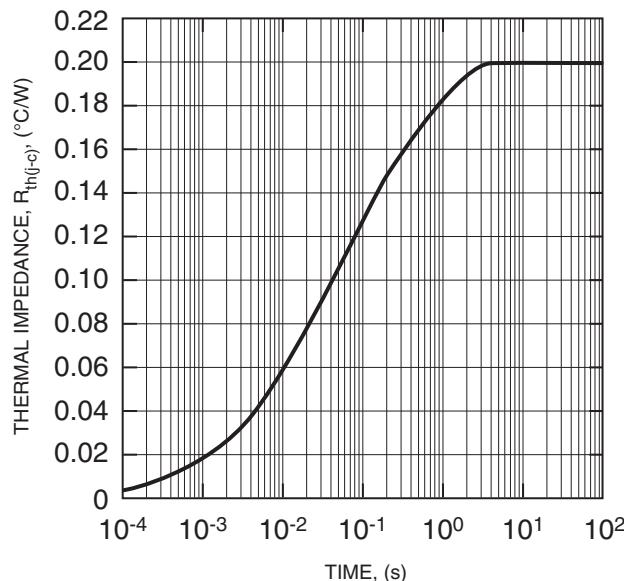
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	Per Diode	—	—	0.20	$^\circ\text{C}/\text{W}$
Thermal Resistance, Case to Sink Lubricated	$R_{th(c-s)Q}$	Per Module	—	—	0.05	$^\circ\text{C}/\text{W}$

QR\_3310002

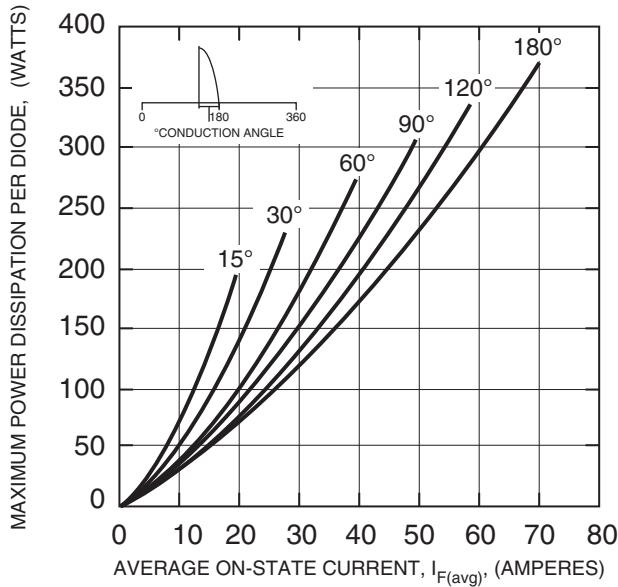
 Fast Recovery Diode Module  
 100 Amperes/3300 Volts

 MAXIMUM ON-STATE FORWARD VOLTAGE DROP CHARACTERISTICS  
 $(T_j = 150^\circ\text{C})$ 


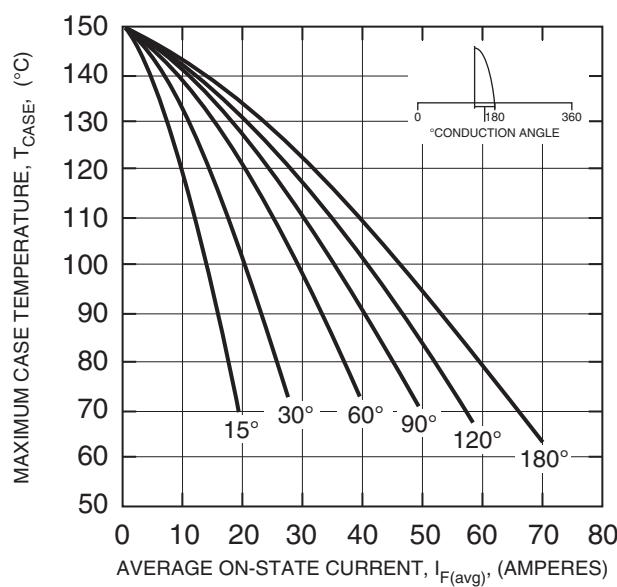
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



QR\_3310002

 Fast Recovery Diode Module  
 100 Amperes/3300 Volts
